

Power Bridge Rectifiers

SKB 30

Features

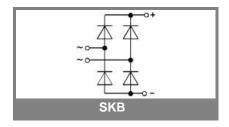
- Isolated metal case with screw terminals
- Blocking voltage up to 1600 V
- High surge current
- Easy chassis mounting
- UL recognized, file no. E 63 532

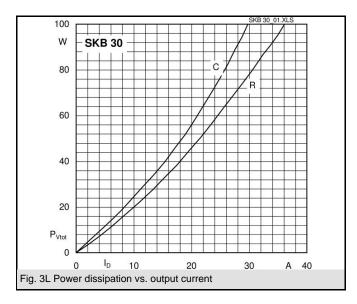
Typical Applications

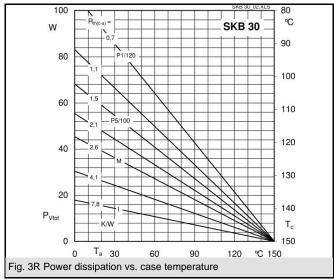
- Single phase rectifiers for power supplies
- Input rectifiers for variable frequency drives
- Rectifiers for DC motor field supplies
- · Battery charger rectifiers
- Recommended snubber network: RC: 0.1 μ F, 50 Ω (P $_{R}$ = 1 W)
- Freely suspended or mounted on an insulator
- 2) Mounted on a painted metal sheet of min. 250 x 250 x 1 mm

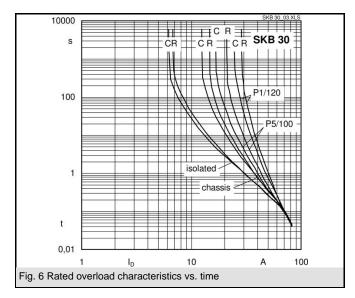
| V _{RSM} , V _{RRM} | V _{VRMS} | I _D = 30 A (T _c = 94 °C) | C _{max} | R _{min} |
|-------------------------------------|-------------------|--|------------------|------------------|
| V | V | Types | μF | Ω |
| 200 | | SKB 30/02A1 | | 0,15 |
| 400 | | SKB 30/04A1 | | 0,3 |
| 800 | | SKB 30/08A1 | | 0,5 |
| 1200 | | SKB 30/12A1 | | 0,75 |
| 1400 | | SKB 30/14A1 | | 0,9 |
| 1600 | | SKB 30/16A1 | | 1 |

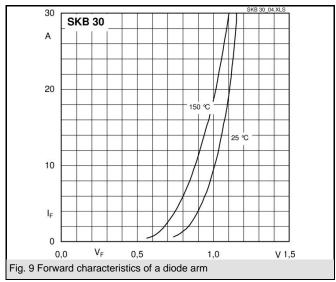
| Symbol | Conditions | Values | Units |
|----------------------|--|-------------------|-------|
| I _D | T _a = 45 °C, isolated ¹⁾ | 6,5 | Α |
| | T _a = 45 °C, chassis ²⁾ | 15 | Α |
| I _{DCL} | T _a = 45 °C, isolated ¹⁾ | 6 | Α |
| | T _a = 45 °C, chassis ²⁾ | 13 | Α |
| | $T_a = {^{\circ}C},$ | | Α |
| I _{FSM} | T _{vi} = 25 °C, 10 ms | 370 | Α |
| | T _{vi} = 150 °C, 10 ms | 320 | Α |
| i²t | T _{vj} = 25 °C, 8,3 10 ms | 680 | A²s |
| | T _{vj} = 150 °C, 8,3 10 ms | 500 | A²s |
| V _F | T _{vj} = 25°C, I _F = 150 A | max. 2,2 | V |
| $V_{(TO)}$ | $T_{vj} = 150^{\circ}C$ | max. 0,85 | V |
| r _T | T _{vj} = 150°C | max. 12 | mΩ |
| I_{RD} | $T_{vj} = 25^{\circ}C, V_{RD} = V_{RRM}$ | 300 | μA |
| | $T_{vj}^{3} = {^{\circ}C}, V_{RD} = V_{RRM} \ge V$ | | μA |
| I_{RD} | $T_{vi} = 150$ °C, $V_{RD} = V_{RRM}$ | 5 | mA |
| | $T_{vi} = {^{\circ}C}, V_{RD} = V_{RRM} \ge V$ | | mA |
| t _{rr} | $T_{vj} = 25^{\circ}C$ | 25 | μs |
| f_G | | 2000 | Hz |
| R _{th(j-a)} | isolated ¹⁾ | 8,5 | K/W |
| . 0 . , | chassis ²⁾ | 3,3 | K/W |
| R _{th(j-c)} | total | 0,7 | K/W |
| R _{th(c-s)} | total | 0,1 | K/W |
| T _{vi} | | - 40 + 150 | °C |
| T _{stg} | | - 55 + 150 | °C |
| V _{isol} | a. c. 50 60 Hz; r.m.s.; 1 s / 1 min. | 3000 / 2500 | V~ |
| M_s | to heatsink | 5 ± 15 % | Nm |
| M _t | to terminals | 1,5 ± 15 % | Nm |
| а | | | m/s² |
| w | | 125 | g |
| Fu | | 25 | А |
| Case | | G 12 | |

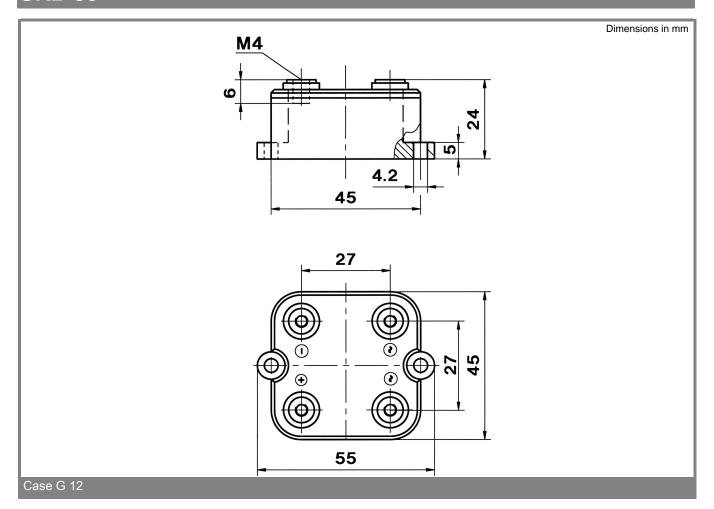












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